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# INTEGRATED CIRCUITS, SILICON MONOLITHIC,

# HCMOS QUAD 2-INPUT NAND GATES,

# WITH OPEN DRAIN OUTPUT,

# **BASED ON TYPE 54HC03**

ESCC Detail Specification No. 9201/114

ISSUE 1 October 2002



Document Custodian: European Space Agency - see https://escies.org



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# HCMOS QUAD 2-INPUT NAND GATES,

# WITH OPEN DRAIN OUTPUT,

## **BASED ON TYPE 54HC03**

ESA/SCC Detail Specification No. 9201/114



# space components coordination group

		Approved by	
lssue/Rev.	Date	SCCG Chairman	ESA Director General or his Deputy
Issue 1	November 1991	Tommens	I Late
Revision 'A'	April 1994	Tomances	1. Jedo
Revision 'B'	August 2001	7.200	Am
Revision 'C'	February 2002	71. 100	- And



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# DOCUMENTATION CHANGE NOTICE

Rev. Letter	Rev. Date	CHANGE Reference Item	Approved DCR No.
'Α'	Apr. '94	<ul> <li>P1. Cover Page</li> <li>P2. DCN</li> <li>P6. Table 1(a) : Lead Material and/or Finish amended.</li> <li>P8. Figure 2(b) : Drawing altered. : Dimension F Max. amended.</li> <li>P13. Notes : Note 13 added.</li> <li>P18. Para. 4.4.2 : Lead Finish, Types amended.</li> </ul>	None None 221050 23541 23541 23541 23541 221050
,В,	Aug. '01	<ul> <li>P1. Cover page</li> <li>P2. DCN</li> <li>P4. T of C</li> <li>P5. Para. 1.3</li> <li>New sentence added.</li> <li>P6. Table 1(a)</li> <li>New variants 10 and 11 added.</li> <li>P7. Figure 2(a)</li> <li>Side Elevation corrected.</li> <li>Dimension 'C' amended.</li> <li>P9. Figure 2(c)</li> <li>In the drawing, Pin No. 20 location corrected.</li> <li>P13. Notes to Figures</li> <li>Title amended to read 2(a) to 2(g).</li> <li>Note 9 text amended to include SO.</li> <li>P13A. Figure 2(g)</li> <li>New Figure added.</li> <li>P14. Figure 3(a)</li> <li>Titles amended to include SO.</li> <li>P18. Para. 4.3.2</li> <li>Para. 4.4.2</li> <li>New sentence inserted after 'No. 23500'.</li> <li>Para. 4.5.2</li> <li>P41. Appendix 'B'</li> <li>Manufacturer reference changed.</li> <li>New deviations added.</li> </ul>	None None 221603 221603 221566 221566 221566 221566 221566 221566 221566 221566 221566 221566 221566 221566 221566 221566 221566 221566 221566 221566 221566
,C,	Feb. '02	P1. Cover page P2. DCN P18. Para. 4.5.2 : Text amended to include SO packages.	None None 23947

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### 1. <u>GENERAL</u>

#### 1.1 <u>SCOPE</u>

This specification details the ratings, physical and electrical characteristics, test and inspection data for a silicon, monolithic, high speed CMOS Quad 2-Input NAND Gate, having fully buffered Open Drain Outputs, based on Type 54HC03. It shall be read in conjunction with ESA/SCC Generic Specification No. 9000, the requirements of which are supplemented herein.

#### 1.2 COMPONENT TYPE VARIANTS

Variants of the basic type integrated circuits specified herein, which are also covered by this specification, are given in Table 1(a).

#### 1.3 MAXIMUM RATINGS

The maximum ratings, which shall not be exceeded at any time during use or storage, applicable to the integrated circuits specified herein, are as scheduled in Table 1(b).

Maximum ratings shall only be exceeded during testing to the extent specified in this specification and when stipulated in Test Methods and Procedures of the applicable ESA/SCC Generic Specification.

### 1.4 PARAMETER DERATING INFORMATION (FIGURE 1)

Not applicable.

- 1.5 <u>PHYSICAL DIMENSIONS</u> As per Figure 2.
- 1.6 <u>PIN ASSIGNMENT</u> As per Figure 3(a).
- 1.7 <u>TRUTH TABLE</u> As per Figure 3(b).
- 1.8 <u>CIRCUIT SCHEMATIC</u> As per Figure 3(c).
- 1.9 <u>FUNCTIONAL DIAGRAM</u>

As per Figure 3(d).

### 1.10 HANDLING PRECAUTIONS

These devices are susceptible to damage by electrostatic discharge. Therefore, suitable precautions shall be employed for protection during all phases of manufacture, testing, packaging, shipment and any handling.

These components are Categorised as Class 2 with a Minimum Critical Path Failure Voltage of 2500 Volts.

### 1.11 INPUT AND OUTPUT PROTECTION NETWORKS

Protection networks shall be incorporated into each input and output as shown in Figure 3(e).



PAGE

# TABLE 1(a) - TYPE VARIANTS

VARIANT	CASE	FIGURE	LEAD MATERIAL AND/OR FINISH
01	FLAT	2(a)	G2 or G8
02	FLAT	2(a)	G4
03	D.I.L.	2(b)	G2 or G8
04	D.I.L.	2(b)	G4
05	CHIP CARRIER	2(c)	2
06	FLAT	2(d)	G4
07	D.I.L.	2(e)	G4
08	CHIP CARRIER	2(f)	7
09	CHIP CARRIER	2(f)	4
10	SO CERAMIC	2(g)	G2
11	SO CERAMIC	2(g)	G4

### TABLE 1(b) - MAXIMUM RATINGS

NO.	CHARACTERISTICS	SYMBOL	MAXIMUM RATINGS	UNITS	REMARKS
1	Supply Voltage	V <sub>DD</sub>	-0.5 to +7.0	V	Note 1
2	Input Voltage	Vin	-0.5 to V <sub>DD</sub> + 0.5	V	Notes 1, 2
3	Output Voltage	VOUT	-0.5 to V <sub>DD</sub> +0.5	V	Notes 1, 3
4	Device Dissipation (Continuous)	PD	300	mW	Note 4
5	Supply Current	IDDop	50	mA	***************************************
6	Operating Temperature Range	T <sub>op</sub>	-55 to +125	°C	T <sub>amb</sub>
7	Storage Temperature Range	T <sub>stg</sub>	-65 to +150	°C	
8	Soldering Temperature For FP and DIP For CCP	T <sub>sol</sub>	+ 265 + 245	°C	Note 5 Note 6

## **NOTES**

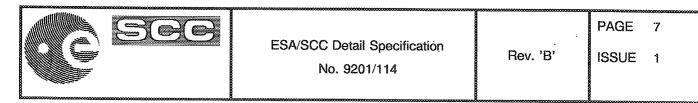
1. Device is functional for  $2.0V \le V_{DD} \le 6.0V$ .

2. Input current limited to  $I_{IC} = \pm 20$ mA.

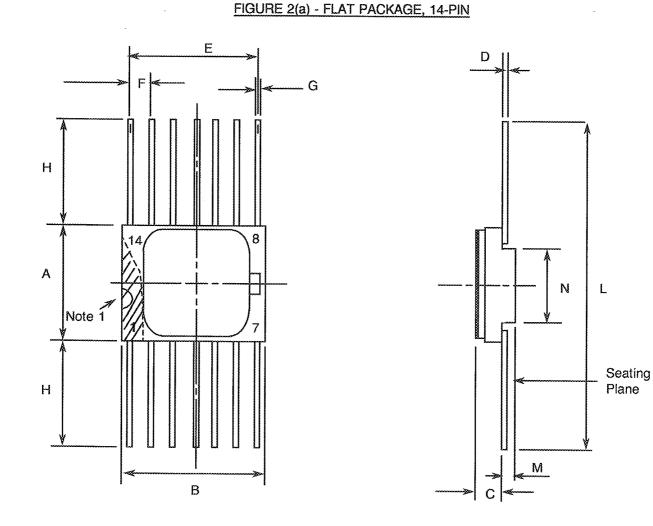
- 3. Output current limited to  $I_{OUT} = \pm 25 \text{mA}$ .
- 4. The maximum device dissipation is determined by IDDop max. (50mA) x 6.0V.
- 5. Duration 10 seconds maximum at a distance of not less than 1.5mm from the device body and the same lead shall not be resoldered until 3 minutes have elapsed.
- 6. Duration 5 seconds maximum and the same terminal shall not be resoldered until 3 minutes have elapsed.

# FIGURE 1 - PARAMETER DERATING INFORMATION

Not applicable.



### FIGURE 2 - PHYSICAL DIMENSIONS



SYMBOL	MILLIMETRES		LIOTEO
STWDUL	MIN	MAX	NOTES
A	6.75	7.06	
В	9.76	10.14	
С	1.49	1.95	
D	0.10	0.15	8
E	7.50	7.75	
F	1.27	TYPICAL	5, 9
G	0.38	0.48	8
н	6.0	~	8
L	18.75	22.0	
М	0.33	0.43	
N	4.31	TYPICAL	

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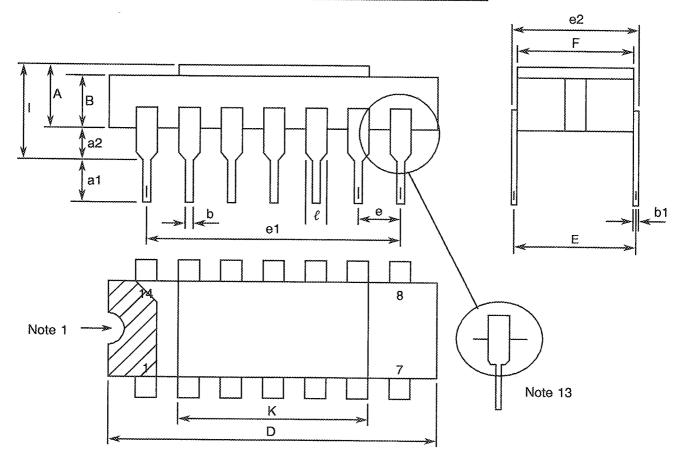
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# FIGURE 2 - PHYSICAL DIMENSIONS (CONTINUED)

#### FIGURE 2(b) - DUAL-IN-LINE PACKAGE, 14-PIN



SYMBOL	MILLIM	NOTEO	
OTMOOL	MIN	MAX	NOTES
A	2.10	2.54	
a1	3.0	3.70	
a2	0.63	1.14	3
В	1.82	2.23	
b	0.40	0.50	8
b1	0.20	0.30	8
D	18.79	19.20	
E	7.36	7.87	
e	2.54 T	/PICAL	6, 9
e1	15.11	15.37	
e2	7.62	8.12	
F	7.11	7.75	
1	-	3.70	
К	10.90	12.10	
l	1.27 T)		8 '

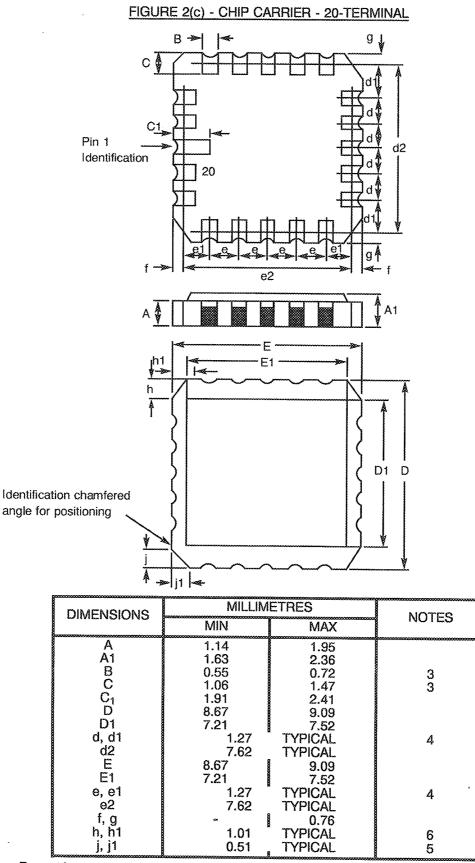
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#### FIGURE 2 - PHYSICAL DIMENSIONS (CONTINUED)



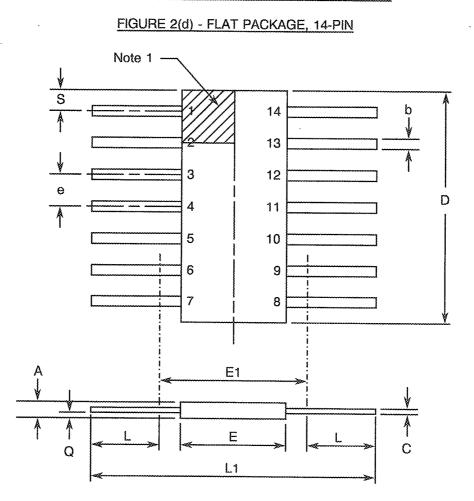
NOTES: See Page 13.



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### FIGURE 2 - PHYSICAL DIMENSIONS (CONTINUED)



SYMBOL	MILLIMETRES		ALOTEO
STWDUL	MIN	MAX	NOTES
A	1.27	2.03	***************************************
b	0.38	0.56	8
С	0.08	0.23	8
D	8.56	8.89	4
E	5.97	6.73	
E1	7.00 T	PICAL	4
e	1.27 T	(PICAL	5, 9
L	6.86	8.0	8
L1	21.34	21.84	
Q	0.51	1.02	2
S	0.25	0.64	7

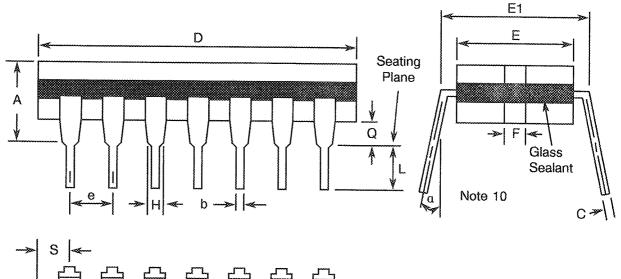
NOTES: See Page 13.

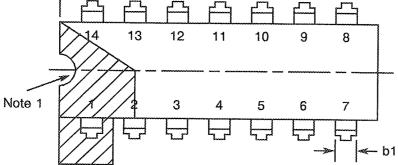


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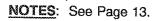
# FIGURE 2 - PHYSICAL DIMENSIONS (CONTINUED)

### FIGURE 2(e) - DUAL-IN-LINE PACKAGE, 14-PIN





SYMBOL	MILLIM	ETRES	NOTTO
UTMBOL	MIN	MAX	NOTES
A	~	5.08	
b	0.38	0.66	8
b1	-	1.78	8
С	0.20	0.44	8
D	19.18	19.94	4
E	6.22	7.62	4
E1	7.37	8.13	
6	2.54 TY	PICAL	6, 9
F	1.27 T	, YPICAL	
н	0.76	-	8
L	3.30	5.08	8
Q	0.51	-	3
S	1.78	2.54	7
a	0°	15°	10

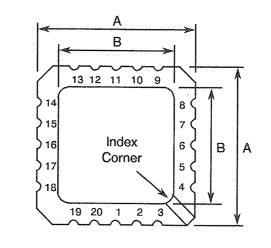


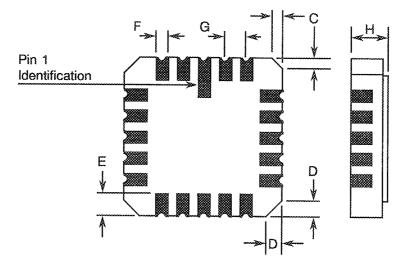


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### FIGURE 2 - PHYSICAL DIMENSIONS (CONTINUED)

# FIGURE 2(f) - SQUARE CHIP CARRIER PACKAGE (3 LAYER BASE), 20-TERMINAL





SYMBOL	MILLIMETRES		NOTES
OT MBOL	MIN	MAX	NOTES
A	8.69	9.09	
В	7.80	9.09	
С	0.25	0.51	11
D	0.89	1.14	12
E	1.14	1.40	8
F	0.56	0.71	8
G	1.27 TYPICAL		5, 9
Н	1.63	2.54	





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### FIGURE 2 - PHYSICAL DIMENSIONS (CONTINUED)

#### NOTES TO FIGURES 2(a) TO 2(g) INCLUSIVE

- 1. Index area: a notch, letter or dot shall be located adjacent to Pin 1 and shall be within the shaded area shown. For chip carrier packages the index shall be as defined in Figures 2(c) and 2(f).
- 2. Dimension Q shall be measured at the point of exit of the lead from the body.
- 3. The dimension shall be measured from the seating plane to the base plane.
- 4. The dimension allows for off-centre lids, meniscus and glass overrun.
- 5. The true position pin or terminal spacing is 1.27mm between centrelines. Each pin or terminal centreline shall be located within ±0.13mm of it's true longitudinal position relative to Pin 1 and the highest pin number.
- 6. The true position pin spacing is 2.54mm between centrelines. Each pin centreline shall be located within  $\pm 0.25$ mm of it's true longitudinal position relative to Pin 1 and the highest pin number.
- 7. Applies to all 4 corners.
- 8. All leads or terminals.
- 9. 12 spaces for flat, SO and dual-in-line packages.

16 spaces for chip carrier packages.

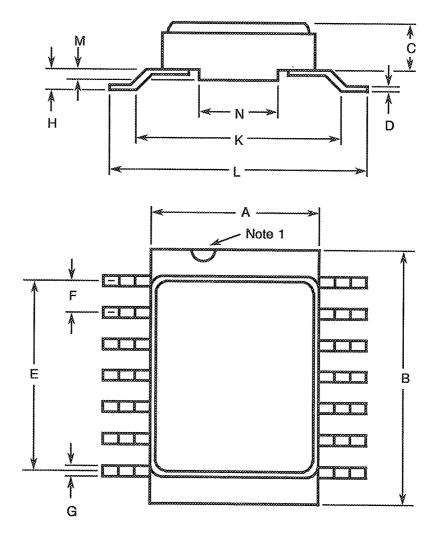
- 10. Lead centreline when a is 0°.
- 11. Index corner only 2 dimensions.
- 12. 3 non-index corners 6 dimensions.
- 13. For all pins, either pin shape may be supplied.



2

# FIGURE 2 - PHYSICAL DIMENSIONS (CONTINUED)

# FIGURE 2(g) - SMALL OUTLINE CERAMIC PACKAGE, 14-PIN



SYMBOL	MILLIM	NOTES	
OTMOOL	MIN.	MAX.	NUTES
A	6.75	7.06	
В	9.76	10.14	
С	1.49	1.95	***************************************
D	0.102	0.152	8
E	7.50	7.75	***************************************
٦	1.27 TY	PICAL	5, 9
G	0.38	0.48	8
Н	0.60	0.90	8
K	9.00 TYI	PICAL	***********************
L	10	10.65	000000000000000000000000000000000000000
M	0.33	0.43	*******
N	4.31 TY	PICAL	555555555555555555555555555555555555555

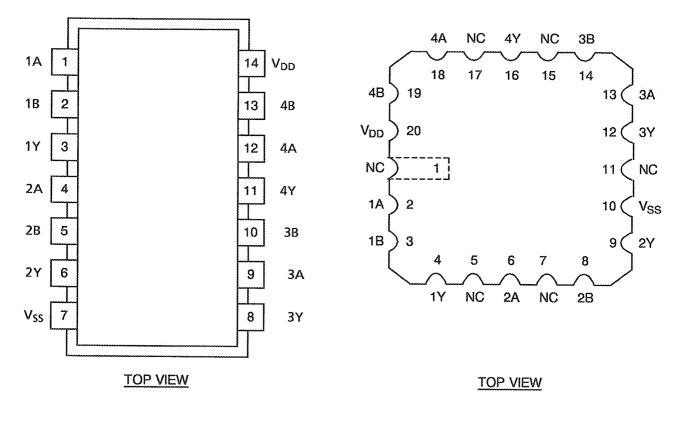
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#### FIGURE 3(a) - PIN ASSIGNMENT

#### DUAL-IN-LINE, SO AND FLAT PACKAGE

CHIP CARRIER PACKAGE

2.-



# FLAT PACKAGE, SO AND DUAL-IN-LINE TO CHIP CARRIER PIN ASSIGNMENT

FLAT PACKAGE, SO AND DUAL-IN-LINE PIN OUTS	1	2	3	4	5	6	7	8	9	10	11	12	13	14
CHIP CARRIER PIN OUTS	2	3	4	6	8	9	10	12	13	14	16	18	19	20

### FIGURE 3(b) - TRUTH TABLE (EACH GATE)

INPI	JTS	OUTPUT
A	В	$Y = \overline{A.B}$
L H L H	L L H H	H H H L

**NOTES** 1. Logic Level Definitions: L = Low Level, H = High Level.



2-

#### FIGURE 3(c) - CIRCUIT SCHEMATIC (EACH GATE)

Not applicable.

#### FIGURE 3(d) - FUNCTIONAL DIAGRAM (1) 1A (3) 1Y $\diamond$ (2) & 1B (4) 2A (6) 2Y (5) 2B (9) ЗA (8) 3Y (10) ЗB (12) 4A (11) 4Y (13) 4B

#### NOTES

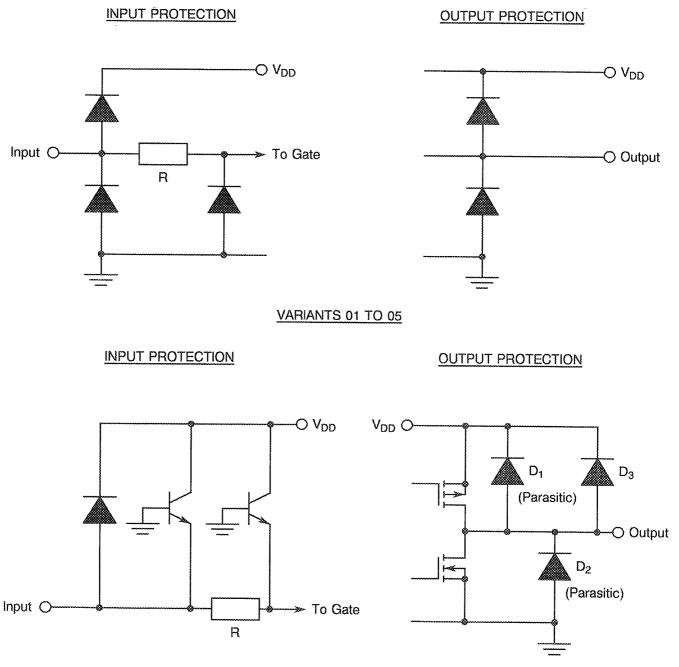
1. Pin numbers shown are for DIP and FP.



2.

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#### FIGURE 3(e) - INPUT AND OUTPUT PROTECTION NETWORKS



VARIANTS 06 TO 09



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#### 2. <u>APPLICABLE DOCUMENTS</u>

The following documents form part of this specification and shall be read in conjunction with it:-

- (a) ESA/SCC Generic Specification No. 9000 for Integrated Circuits.
- (b) MIL-STD-883, Test Methods and Procedures for Micro-electronics.

#### 3. <u>TERMS, DEFINITIONS, ABBREVIATIONS, SYMBOLS AND UNITS</u>

For the purpose of this specification, the terms, definitions, abbreviations, symbols and units specified in ESA/SCC Basic Specification No. 21300 shall apply. In addition, the following symbols are used:

- VIC = Input Clamp Voltage.
- I<sub>IC</sub> = Input Clamp Diode Current.

#### 4. <u>REQUIREMENTS</u>

#### 4.1 GENERAL

The complete requirements for procurement of the integrated circuits specified herein are stated in this specification and ESA/SCC Generic Specification No. 9000 for Integrated Circuits. Deviations from the Generic Specification, applicable to this specification only, are listed in Para. 4.2.

Deviations from the applicable Generic Specification and this Detail Specification, formally agreed with specific Manufacturers on the basis that the alternative requirements are equivalant to the ESA/SCC requirements and do not affect the components' reliability, are listed in the appendices attached to this specification.

#### 4.2 DEVIATIONS FROM GENERIC SPECIFICATION

#### 4.2.1 Deviations from Special In-process Controls

- (a) Para. 5.2.2, Total Dose Irradiation Testing: Shall be performed during irradiation qualification and maintenance of qualification.
- (b) Para. 5.2.2, Total Dose Irradiation Testing: Shall be performed during procurement on an irradiation lot acceptance basis at the total dose irradiation level specified in the Purchase Order.

# 4.2.2 <u>Deviations from Final Production Tests (Chart II)</u> None.

- 4.2.3 <u>Deviations from Burn-in Tests (Chart III)</u> None.
- 4.2.4 <u>Deviations from Qualification Tests (Chart IV)</u> None.



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# 4.2.5 Deviations from Lot Acceptance Tests (Chart V)

None.

### 4.3 <u>MECHANICAL REQUIREMENTS</u>

#### 4.3.1 Dimension Check

The dimensions of the integrated circuits specified herein shall be checked. They shall conform to those shown in Figure 2.

#### 4.3.2 Weight

The maximum weight of the integrated circuits specified herein shall be 2.2 grammes for the dual-in-line package, 0.7 grammes for the flat and SO packages and 0.6 grammes for the chip carrier package.

#### 4.4 MATERIALS AND FINISHES

The materials shall be as specified herein. Where a definite material is not specified, a material which will enable the integrated circuits specified herein to meet the performance requirements of this specification shall be used. Acceptance or approval of any constituent material does not guarantee acceptance of the finished product.

#### 4.4.1 <u>Case</u>

The case shall be hermetically sealed and have a metal body with hard glass seals or a ceramic body and the lids shall be welded, brazed, preform-soldered or glass frit sealed.

#### 4.4.2 Lead Material and Finish

For dual-in-line and flat packages, the material shall be Type 'G' with either Type '4' or Type '2 or 8' finish in accordance with the requirements of ESA/SCC Basic Specification No. 23500. For chip carrier packages the finish shall be Type '2', Type '4' or Type '7' in accordance with the requirements of ESA/SCC Basic Specification No. 23500. For SO ceramic packages, the material shall be Type 'G' with either Type '2' or Type '4' finish in accordance with the requirements of ESA/SCC Basic Specification No. 23500. For SO ceramic packages, the material shall be Type 'G' with either Type '2' or Type '4' finish in accordance with the requirements of ESA/SCC Basic Specification No. 23500. (See Table 1(a) for Type Variants).

#### 4.5 MARKING

#### 4.5.1 General

The marking of all components delivered to this specification shall be in accordance with the requirements of ESA/SCC Basic Specification No. 21700. Each component shall be marked in respect of:-

- (a) Lead Identification.
- (b) The SCC Component Number.
- (c) Traceability Information.

#### 4.5.2 Lead Identification

For dual-in-line, flat and SO packages an index shall be located at the top of the package in the position defined in Note 1 to Figure 2 or, alternatively, a tab may be used to identify Pin No. 1. The pin numbering must be read with the index or tab on the left-hand side. For chip carrier packages, the index shall be as defined by Figures 2(c) and 2(f).



### 4.5.3 The SCC Component Number

Each component shall bear the SCC Component Number which shall be constituted and marked as follows:

	920111401 BF
Detail Specification Number	
Type Variant (see Table 1(a))	
Testing Level (B or C, as applicable)	
Type Variant (see Table 1(a))	

The Total Dose Irradiation Level designation shall be added for those devices for which a sample has been successfully tested to the level in question. For these devices, a code letter shall be added in accordance with the requirements of ESA/SCC Basic Specification No. 22900.

#### 4.5.4 Traceability Information

Each component shall be marked in respect of traceability information in accordance with the requirements of ESA/SCC Basic Specification No. 21700.

#### 4.6 ELECTRICAL MEASUREMENTS

#### 4.6.1 <u>Electrical Measurements at Room Temperature</u>

The parameters to be measured in respect of electrical characteristics are scheduled in Table 2. Unless otherwise specified, the measurements shall be performed at  $T_{amb} = +22 \pm 3$  °C.

#### 4.6.2 Electrical Measurements at High and Low Temperatures

The parameters to be measured at high and low temperatures are scheduled in Table 3. The measurements shall be performed at  $T_{amb} = +125 (+0.5) \circ C$  and  $-55 (+5.0) \circ C$  respectively.

#### 4.6.3 <u>Circuits for Electrical Measurements</u>

Circuits and test sequences for use in performing electrical measurements listed in Tables 2 and 3 of this specification are shown in Figure 4.

#### 4.7 <u>BURN-IN TESTS</u>

#### 4.7.1 Parameter Drift Values

The parameter drift values applicable to H.T.R.B. and Power Burn-in are specified in Table 4 of this specification. Unless otherwise stated, measurements shall be performed at  $T_{amb} = +22 \pm 3$  °C. The parameter drift values ( $\Delta$ ) applicable to the parameters scheduled, shall not be exceeded. In addition to these drift value requirements, the appropriate limit value specified for a given parameter in Table 2 shall not be exceeded.

For H.T.R.B. Burn-in, the parameter drift values ( $\Delta$ ) shall be applied before the N-Channel (0 hours) and after the P-Channel (144 hours) burn-in.

#### 4.7.2 Conditions for H.T.R.B. and Power Burn-in

The requirements for H.T.R.B. and Power Burn-in are specified in Section 7 of ESA/SCC Generic Specification No. 9000. The conditions for H.T.R.B. and Power Burn-in shall be as specified in Tables 5(a), 5(b) and 5(c) of this specification.

#### 4.7.3 Electrical Circuits for H.T.R.B. and Power Burn-in

Circuits for use in performing the H.T.R.B. and Power Burn-in tests are shown in Figures 5(a), 5(b) and 5(c) of this specification.



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# TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - d.c. PARAMETERS

NO.	CHARACTERISTICS	SYMBOL	TEST METHOD	TEST	TEST CONDITIONS (PINS UNDER TEST	LIN	ITS	
		UTIMBOL	MIL-STD 883	FIG.	D/F = DIP AND FP C = CCP)	MIN	MAX	UNIT
1	Functional Test 1	-	-	3(b)	Verify Truth Table without Load. $V_{IL} = 0.3V, V_{IH} = 1.5V$ $V_{DD} = 2.0V, V_{SS} = 0V$ $t_r < 1.0 \mu s, f = 10 kHz (min)$ Note 1	-	~	-
2	Functional Test 2	-	-	3(b)	Verify Truth Table without Load. $V_{IL} = 0.9V, V_{IH} = 3.15V$ $V_{DD} = 4.5V, V_{SS} = 0V$ $t_r = t_f < 500ns$ f = 10kHz (min) Note 1	-	-	-
3	Functional Test 3	-	-	3(b)	Verify Truth Table without Load. $V_{IL} = 1.2V, V_{IH} = 4.2V$ $V_{DD} = 6.0V, V_{SS} = 0V$ $t_r = t_f < 400ns$ f = 10kHz (min) Note 1	-	~	-
4 to 5	Quiescent Current	dal	3005	4(a)	$V_{IL} = 0V, V_{IH} = 6.0V$ $V_{DD} = 6.0V, V_{SS} = 0V$ All Outputs Open (Pin D/F 14) (Pin C 20)	-	0.1	μΑ
6 to 13	Input Current Low Level	Ι <sub>ΙĽ</sub>	3009	4(b)		~	-50	nA
14 to 21	Input Current High Level	lιΗ	3010	4(c)	$\begin{array}{l} V_{IN} \; (\text{Under Test}) \; = \; 6.0 \text{V} \\ V_{IN} \; (\text{Remaining Inputs}) \\ = \; 0 \text{V} \\ V_{DD} \; = \; 6.0 \text{V}, \; V_{SS} \; = \; 0 \text{V} \\ (\text{Pins D/F 1-2-4-5-9-10-12-13}) \\ (\text{Pins C 2-3-6-8-13-14-18-19}) \end{array}$	- ,	50	nA

NOTES: See Page 22.



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# TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - d.c. PARAMETERS (CONT'D)

			TEST METHOD	TEST	TEST CONDITIONS (PINS UNDER TEST	LIN	IITS	
NO.	CHARACTERISTICS	SYMBOL	MIL-STD 883	FIG.	D/F = DIP AND FP C = CCP	MIN	МАХ	UNIT
22 to 25	Output Voltage Low Level 1	V <sub>OL1</sub>	3007	4(d)	Gate Under Test: $V_{IN} = 1.5V$ , $I_{OL} = 20\mu A$ All Other Gates: $V_{IN} = 0V$ $V_{DD} = 2.0V$ , $V_{SS} = 0V$ (Pins D/F 3-6-8-11) (Pins C 4-9-12-16)	~	0.1	V
26 to 29	Output Voltage Low Level 2	V <sub>OL2</sub>	3007	4(d)	Gate Under Test: $V_{IN} = 3.15V$ , $I_{OL} = 20\mu A$ All other Gates: $V_{IN} = 0V$ $V_{DD} = 4.5V$ , $V_{SS} = 0V$ (Pins D/F 3-6-8-11) (Pins C 4-9-12-16)	-	0.1	V
30 to 33	Output Voltage Low Level 3	V <sub>OL3</sub>	3007	4(d)	Gate Under Test: $V_{IN} = 4.2V$ , $I_{OL} = 20\mu A$ All other Gates: $V_{IN} = 0V$ $V_{DD} = 6.0V$ , $V_{SS} = 0V$ (Pins D/F 3-6-8-11) (Pins C 4-9-12-16)	-	0.1	V
34 to 37	Output Voltage Low Level 4	V <sub>OL4</sub>	3007	4(d)	Gate Under Test: $V_{IN} = 3.15V$ , $I_{OL} = 4.0mA$ All other Gates: $V_{IN} = 0V$ $V_{DD} = 4.5V$ , $V_{SS} = 0V$ (Pins D/F 3-6-8-11) (Pins C 4-9-12-16)	-	0.26	V
38 to 41	Output Voltage Low Level 5	V <sub>OL5</sub>	3007	4(d)	Gate Under Test: $V_{IN} = 4.2V, I_{OL} = 5.2mA$ All other Gates: $V_{IN} = 0V$ $V_{DD} = 6.0V, V_{SS} = 0V$ (Pins D/F 3-6-8-11) (Pins C 4-9-12-16)	-	0.26	V
42 to 45	Output Current High Level	Юн	3006	4(e)	Gate Under Test: $V_{IN1} = 4.2V, V_{IN2} = 1.2V$ $V_{OUT} = 6.0V$ All other Gates: $V_{IN} = 0V$ $V_{DD} = 6.0V, V_{SS} = 0V$ (Pins D/F 3-6-8-11) (Pins C 4-9-12-16)	- ,	0.5	μΑ



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# TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - d.c. PARAMETERS (CONT'D)

NO.	CHARACTERISTICS	SYMBOL	TEST METHOD	TEST	TEST CONDITIONS (PINS UNDER TEST	LIM	IITS	- UNIT
		01111002	MIL-STD 883	FIG.	D/F = DIP AND FP C = CCP)	MIN	MAX	
46	Threshold Voltage N-Channel	V <sub>THN</sub>	-	4(f)	1A Input at Ground All Other Inputs: $V_{IN} = 5.0V$ $V_{DD} = 5.0V$ , $I_{SS} = -10\mu A$ (Pin D/F 7) (Pin C 10)	-0.45	-1.45	V
47	Threshold Voltage P-Channel	V <sub>THP</sub>	-	4(g)	1A and 1B Inputs at Ground All Other Inputs: $V_{IN} = -5.0Vdc$ $V_{SS} = -5.0V, I_{DD} = 10\mu A$ (Pin D/F 14) (Pin C 20)	0.45	1.35	V
48 to 55	Input Clamp Voltage (to V <sub>SS</sub> )	V <sub>IC1</sub>	-	4(h)	$\begin{array}{l} I_{\rm IN} \; ({\rm Under \; Test}) = ~0.1 {\rm mA} \\ V_{\rm DD} = \; {\rm Open}, \; V_{\rm SS} \; = 0 {\rm V} \\ {\rm All \; Other \; Pins \; Open} \\ ({\rm Pins \; D/F \; 1-2-4-5-9-10-12-13}) \\ ({\rm Pins \; C \; 2-3-6-8-13-14-18-19}) \end{array}$	-0.4	-0.9	V
56 to 63	Input ClampVoltage (to V <sub>DD</sub> )	V <sub>IC2</sub>	-	4(h)	$      I_{IN} (Under Test) = 0.1mA       V_{DD} = 0V, V_{SS} = Open,       All Other Pins Open       (Pins D/F 1-2-4-5-9-10-12-       13)       (Pins C 2-3-6-8-13-14-18-       19)                             $	0.4	0.9	V

#### <u>NOTES</u>

1. Maximum time to output comparator strobe 30µs.

2. Guaranteed but not tested.

3. Measurements shall be performed on a 100% basis go-no-go, with read and record on a sample basis, LTPD7 (32 pieces) after Chart III (Burn-in) Tests.



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# TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - a.c. PARAMETERS

NO.	CHARACTERISTICS	SYMBOL	TEST METHOD	TEST	TEST CONDITIONS (PINS UNDER TEST	LIN	ITS	
		OT MEOL	MIL-STD 883	FIG.	D/F = DIP AND FP C = CCP)	MIN	мах	UNIT
64 to 71	Input Capacitance	C <sub>IN</sub>	3012	4(i)	$\begin{array}{l} V_{\rm IN} \; ({\rm Not \ Under \ Test}) \\ = 0 V dc \\ V_{\rm DD} \; = \; V_{\rm SS} \; = \; 0 V \\ {\rm Note \ 2} \\ ({\rm Pins \ D/F \ 1-2-4-5-9-10-12-13}) \\ ({\rm Pins \ C \ 2-3-6-8-13-14-18-19}) \end{array}$	-	10	pF
72	Propagation Delay Low to High (1B to 1Y)	t <sub>PLH</sub>	3003	4(j)	$\begin{array}{llllllllllllllllllllllllllllllllllll$	~	25	ns
73	Propagation Delay High to Low (1B to 1Y)	ţыг	3003	4(j)	$\begin{array}{llllllllllllllllllllllllllllllllllll$	-	20	ns
74	Transition Time Low to High	tт∟н	3004	4(j)	Gate Under Test: $V_{IN1} = Pulse$ Generator $V_{IN2} = V_{DD}$ $V_{IN}$ (Remaining Inputs) = 0V $V_{DD} = 4.5V$ , $V_{SS} = 0V$ Note 3 (Pin D/F 3) (Pin C 4)	-	15	ns
75	Transition Time High to Low	t <sub>THL</sub>	3004	4(j)	Gate Under Test: $V_{IN1} = Pulse Generator$ $V_{IN2} = V_{DD}$ $V_{IN}$ (Remaining Inputs) = 0V $V_{DD} = 4.5V$ , $V_{SS} = 0V$ Note 3 (Pin D/F 3) (Pin C 4)	-	15	ns



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# TABLE 3 - ELECTRICAL MEASUREMENTS AT HIGH AND LOW TEMPERATURES

			TEST METHOD	TEST	TEST CONDITIONS (PINS UNDER TEST	LIN	AITS	
NO.	CHARACTERISTICS	SYMBOL	MIL-STD 883	FIG.	D/F = DIP AND FP C = CCP	MIN	МАХ	UNIT
1	Functional Test 1	-	-	3(b)	Verify Truth Table without Load. $V_{IL} = 0.3V, V_{IH} = 1.5V$ $V_{DD} = 2.0V, V_{SS} = 0V$ $t_r < 1.0\mu s, f = 10 kHz (min)$ Note 1	-	~	-
2	Functional Test 2	T	-	3(b)	Verify Truth Table without Load. $V_{IL} = 0.9V, V_{IH} = 3.15V$ $V_{DD} = 4.5V, V_{SS} = 0V$ $t_r = t_f < 500ns$ f = 10kHz (min) Note 1		-	-
3	Functional Test 3	-	-	3(b)	Verify Truth Table without Load. $V_{IL} = 1.2V, V_{IH} = 4.2V$ $V_{DD} = 6.0V, V_{SS} = 0V$ $t_r = t_f < 400ns$ f = 10kHz (min) Note 1	•	-	-
4 to 5	Quiescent Current	IDD	3005	4(a)	$V_{IL} = 0V, V_{IH} = 6.0V$ $V_{DD} = 6.0V, V_{SS} = 0V$ All Outputs Open (Pin D/F 14) (Pin C 20)	~	2.0	μΑ
6 to 13	Input Current Low Level	I <sub>IL</sub>	3009	4(b)	$V_{IN} \text{ (Under Test) } = 0V$ $V_{IN} \text{ (Remaining Inputs)}$ = 6.0V $V_{DD} = 6.0V, V_{SS} = 0V$ (Pins D/F 1-2-4-5-9-10-12- 13) (Pins C 2-3-6-8-13-14-18- 19)	-	-1.0	μΑ
14 to 21	Input Current High Level	Ι <sub>ΙΗ</sub>	3010	4(c)	$\begin{array}{l} V_{IN} \; (\text{Under Test}) \; = \; 6.0 \text{V} \\ V_{IN} \; (\text{Remaining Inputs}) \\ = \; 0 \text{V} \\ V_{DD} \; = \; 6.0 \text{V}, \; V_{SS} \; = \; 0 \text{V} \\ (\text{Pins D/F 1-2-4-5-9-10-12-13}) \\ (\text{Pins C 2-3-6-8-13-14-18-19}) \end{array}$	-	1.0	μA

NOTES: See Page 22.



# TABLE 3 - ELECTRICAL MEASUREMENTS AT HIGH AND LOW TEMPERATURES (CONT'D)

NO.	CHARACTERISTICS	SYMBOL	TEST METHOD	TEST	TEST CONDITIONS (PINS UNDER TEST	LIN	IITS	UNIT
			MIL-STD 883	FIG.	D/F = DIP AND FP C = CCP)	MIN	MAX	
22 to 25	Output Voltage Low Level 1	V <sub>OL1</sub>	3007	4(d)	Gate Under Test: $V_{IN} = 1.5V$ , $I_{OL} = 20\mu A$ All Other Gates: $V_{IN} = 0V$ $V_{DD} = 2.0V$ , $V_{SS} = 0V$ (Pins D/F 3-6-8-11) (Pins C 4-9-12-16)	-	0.1	V
26 to 29	Output Voltage Low Level 2	V <sub>OL2</sub>	3007	4(d)	Gate Under Test: $V_{IN} = 3.15V$ , $I_{OL} = 20\mu A$ All other Gates: $V_{IN} = 0V$ $V_{DD} = 4.5V$ , $V_{SS} = 0V$ (Pins D/F 3-6-8-11) (Pins C 4-9-12-16)	-	0.1	V
30 to 33	Output Voltage Low Level 3	V <sub>OL3</sub>	3007	4(d)	Gate Under Test: $V_{IN} = 4.2V$ , $I_{OL} = 20\mu A$ All other Gates: $V_{IN} = 0V$ $V_{DD} = 6.0V$ , $V_{SS} = 0V$ (Pins D/F 3-6-8-11) (Pins C 4-9-12-16)	-	0.1	V
34 to 37	Output Voltage Low Level 4	V <sub>OL4</sub>	3007	4(d)	Gate Under Test: $V_{IN} = 3.15V$ , $I_{OL} = 4.0mA$ All other Gates: $V_{IN} = 0V$ $V_{DD} = 4.5V$ , $V_{SS} = 0V$ (Pins D/F 3-6-8-11) (Pins C 4-9-12-16)	~	0.4	V
38 to 41	Output Voltage Low Level 5	V <sub>OL5</sub>	3007	4(d)	Gate Under Test: $V_{IN} = 4.2V$ , $I_{OL} = 5.2mA$ All other Gates: $V_{IN} = 0V$ $V_{DD} = 6.0V$ , $V_{SS} = 0V$ (Pins D/F 3-6-8-11) (Pins C 4-9-12-16)	-	0.4	V
42 to 45	Output Current High Level	Юн	3006	4(e)	Gate Under Test: $V_{IN1} = 4.2V, V_{IN2} = 1.2V$ $V_{OUT} = 6.0V$ All other Gates: $V_{IN} = 0V$ $V_{DD} = 6.0V, V_{SS} = 0V$ (Pins D/F 3-6-8-11) (Pins C 4-9-12-16)	•	10	μA



# TABLE 3 - ELECTRICAL MEASUREMENTS AT HIGH AND LOW TEMPERATURES (CONT'D)

NO. CHARACTERISTIC	CHARACTERISTICS	SYMBOL	TEST METHOD	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST D/F = DIP AND FP C = CCP)	LIM	IITS	UNIT
	NO. UNANAUTERISTICS ST	UTIMBOL .	MIL-STD 883			MIN	МАХ	
48 to 55	Input Clamp Voltage (to V <sub>SS</sub> )	V <sub>IC1</sub>	-	4(h)	$    I_{IN} \text{ (Under Test)} = -0.1\text{mA} \\      V_{DD} = \text{Open, } V_{SS} = 0\text{V} \\      All \text{ Other Pins Open} \\      (Pins D/F 1-2-4-5-9-10-12-13) \\      (Pins C 2-3-6-8-13-14-18-19) $	-0.1	-1.2	V
56 to 63	Input ClampVoltage (to V <sub>DD</sub> )	V <sub>IC2</sub>		4(h)	$\begin{split} I_{\text{IN}} & (\text{Under Test}) &= 0.1\text{mA} \\ V_{\text{DD}} &= 0\text{V}, \ V_{\text{SS}} &= \text{Open}, \\ \text{All Other Pins Open} \\ & (\text{Pins D/F 1-2-4-5-9-10-12-13}) \\ & (\text{Pins C 2-3-6-8-13-14-18-19}) \end{split}$	0.1	1.2	V

NOTES: See Page 22.

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### FIGURE 4 - CIRCUITS FOR ELECTRICAL MEASUREMENTS

#### FIGURE 4(a) - QUIESCENT CURRENT TEST TABLE

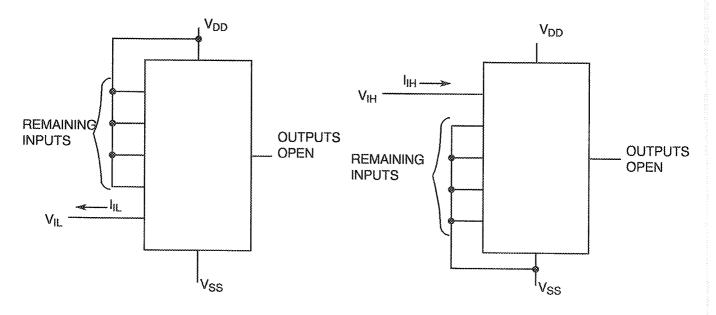
PATTERN	INPUTS						OUTPUTS			;	PACKAGE	D.C. SUPPLY			
NO.	1 2	2 3	4 6	5 8	9 13	10 14	12 18	13 19	3 4	-	8 12	11 16	DIL, FP CCP	7 10	14 20
1	1	1	1	1	1	ľ	1	1		OP	EN			V <sub>SS</sub>	V <sub>DD</sub>
2	0	0	0	0	0	0	0	0		OP	EN			*	w.

#### **NOTES**

- 1. Figure 4(a) illustrates one series of test patterns. Any other pattern series must be agreed with the Qualifying Space Agency and shall be included as an Appendix.
- 2. Logic Level Definitions:  $1 = V_{IH} = V_{DD}$ ,  $0 = V_{IL} = V_{SS}$ .

FIGURE 4(b) - INPUT CURRENT LOW LEVEL

FIGURE 4(c) - INPUT CURRENT HIGH LEVEL



#### **NOTES**

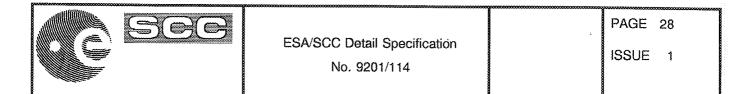
1. Each input to be tested separately.

#### **NOTES**

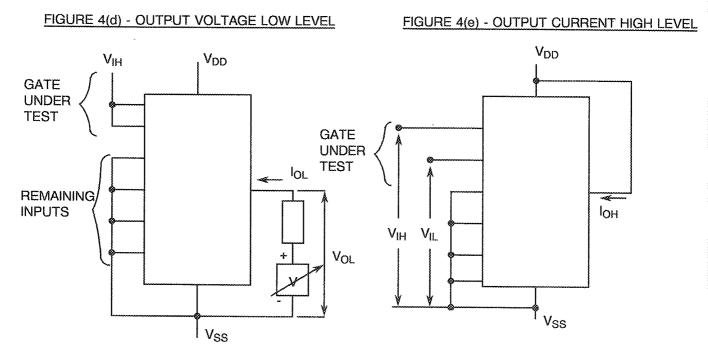
1. Each input to be tested separately.

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#### FIGURE 4 - CIRCUITS FOR ELECTRICAL MEASUREMENTS (CONTINUED)

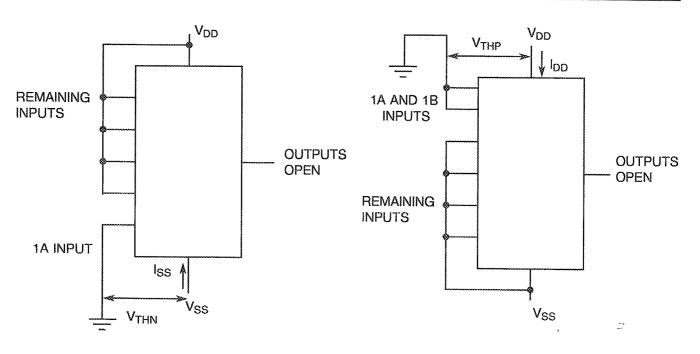


### **NOTES**

1. Each output to be tested separately.

**NOTES** 1. Each output to be tested separately.

# FIGURE 4(f) - THRESHOLD VOLTAGE N-CHANNEL FIGURE 4(g) - THRESHOLD VOLTAGE P-CHANNEL

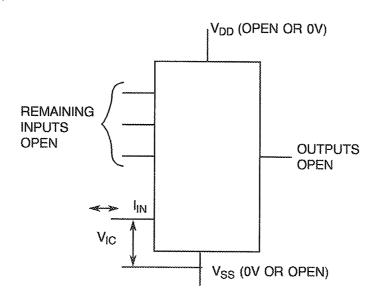




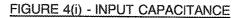
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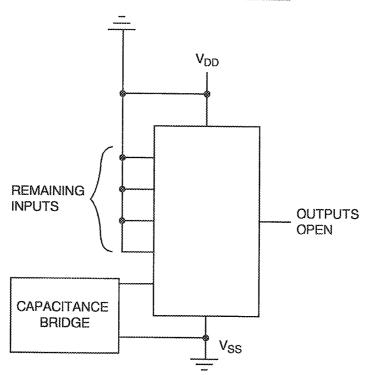
# FIGURE 4 - CIRCUITS FOR ELECTRICAL MEASUREMENTS (CONTINUED)

#### FIGURE 4(h) - INPUT CLAMP VOLTAGE

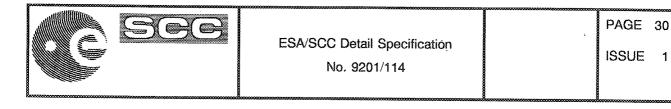


NOTES 1. Each input to be tested separately.

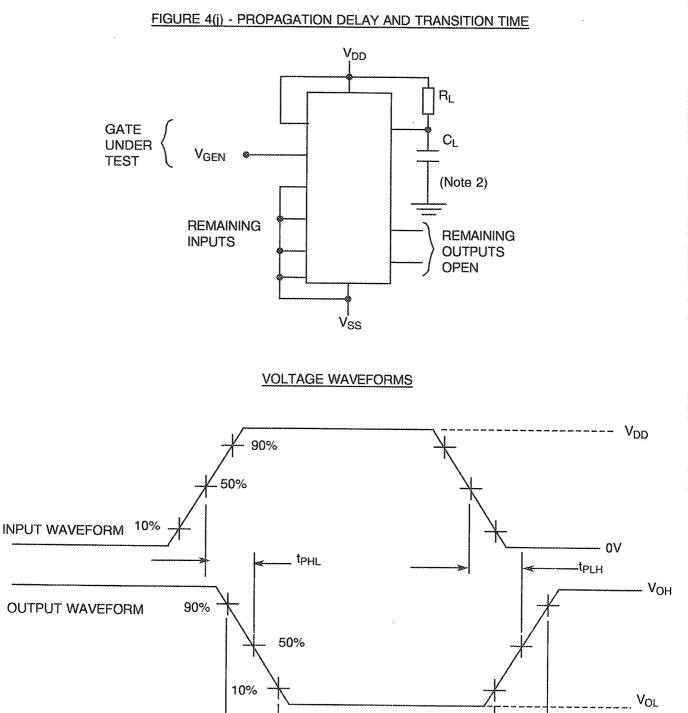




**NOTES** 1. Each input to be tested separately. 2. f = 100KHz to 1MHz.



# FIGURE 4 - CIRCUITS FOR ELECTRICAL MEASUREMENTS (CONTINUED)



#### <u>NOTES</u>

1. Pulse Generator - V<sub>P</sub> = 0 to V<sub>DD</sub>, t<sub>f</sub> and t<sub>f</sub>  $\leq$  6ns, f = 1.0MHz minimum, 50% Duty Cycle, Z<sub>OUT</sub> = 50 $\Omega$ . 2. R<sub>L</sub> = 1k $\Omega$ , C<sub>L</sub> = 50pF ± 5% including scope, wiring and stray capacitance without package in test fixture.

- <sup>t</sup>THL

- t<sub>TLH</sub>



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# TABLE 4 - PARAMETER DRIFT VALUES

NO.	CHARACTERISTICS	SYMBOL	SPEC. AND/OR TEST METHOD	TEST CONDITIONS	CHANGE LIMITS (Δ)	UNIT
4 to 5	Quiescent Current	I <sub>DD</sub>	As per Table 2	As per Table 2	± 30	nA
6 to 13	Input Current Low Level	I <sub>IL</sub>	As per Table 2	As per Table 2	±20	nA
14 to 21	Input Current High Level	IIH	As per Table 2	As per Table 2	±20	nA
34 to 37	Output Voltage Low Level 4	V <sub>OL4</sub>	As per Table 2	As per Table 2	±0.026	V
42 to 45	Output Current High Level	Юн	As per Table 2	As per Table 2	±0.2	μA
46	Threshold Voltage N-Channel	V <sub>THN</sub>	As per Table 2	As per Table 2	± 0.3	V
47	Threshold Voltage P-Channel	V <sub>THP</sub>	As per Table 2	As per Table 2	± 0.3	V



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### TABLE 5(a) - CONDITIONS FOR BURN-IN HIGH TEMPERATURE REVERSE BIAS, N-CHANNELS

NO.	CHARACTERISTICS	SYMBOL	CONDITION	UNIT
1	Ambient Temperature	T <sub>amb</sub>	+ 125( + 0-5)	°C
2	Outputs - (Pins D/F 3-6-8-11) (Pins C 4-9-12-16)	Vout	Open or V <sub>SS</sub>	-
3	Inputs - (Pins D/F 1-2-4-5-9-10-12-13) (Pins C 2-3-6-8-13-14-18-19)	V <sub>IN</sub>	V <sub>SS</sub>	V
4	Positive Supply Voltage (Pin D/F 14) (Pin C 20)	V <sub>DD</sub>	6.0( + 0-0.5)	V
5	Negative Supply Voltage (Pin D/F 7) (Pin C 10)	V <sub>SS</sub>	0	V
6	Duration	t	72	Hours

#### <u>NOTES</u>

1. Input Protection Resistor =  $680\Omega$  min. to  $47k\Omega$  max.

2. Output Load =  $1k\Omega min$ . to  $10k\Omega max$ .

# TABLE 5(b) - CONDITIONS FOR BURN-IN HIGH TEMPERATURE REVERSE BIAS, P-CHANNELS

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NO.	CHARACTERISTICS	SYMBOL	CONDITION	UNIT
1	Ambient Temperature	Tamb	+ 125( + 0-5)	°C
2	Outputs - (Pins D/F 3-6-8-11) (Pins C 4-9-12-16)	V <sub>OUT</sub>	Open or V <sub>DD</sub>	-
3	Inputs - (Pins D/F 1-2-4-5-9-10-12-13) (Pins C 2-3-6-8-13-14-18-19)	V <sub>IN</sub>	V <sub>DD</sub>	V
4	Positive Supply Voltage (Pin D/F 14) (Pin C 20)	V <sub>DD</sub>	6.0( + 0-0.5)	V
5	Negative Supply Voltage (Pin D/F 7) (Pin C 10)	V <sub>SS</sub>	0	V
6	Duration	t	72	Hours

#### <u>NOTES</u>

1. Input Protection Resistor =  $680\Omega$  min. to  $47k\Omega$  max.

2. Output Load =  $1k\Omega$  min. to  $10k\Omega$  max.



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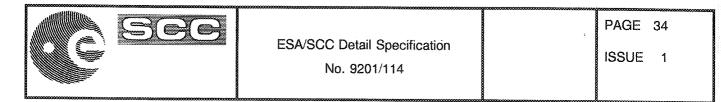
#### TABLE 5(c) - CONDITIONS FOR POWER BURN-IN AND OPERATING LIFE TEST

NO.	CHARACTERISTICS	SYMBOL	CONDITIONS	UNIT
1	Ambient Temperature	Tamb	+ 125( + 0-5)	°C
2	Outputs - (Pins D/F 3-6-8-11) (Pins C 4-9-12-16)	V <sub>OUT</sub>	V <sub>DD</sub>	V
3	Inputs - (Pins D/F 1-4-9-12) (Pins C 2-6-13-18)	V <sub>IN</sub>	V <sub>DD</sub>	V
4	Inputs - (Pins D/F 2-5-10-13) (Pins C 3-8-14-19)	V <sub>IN</sub>	V <sub>GEN</sub>	Vac
5	Pulse Voltage	V <sub>GEN</sub>	0V to V <sub>DD</sub>	Vac
6	Pulse Frequency Square Wave	f	100k ±10% 50 ± 15% Duty Cycle $t_r = t_f \le 400$ ns	Hz
7	Positive Supply Voltage (Pin D/F 14) (Pin C 20)	V <sub>DD</sub>	6.0( + 0-0.5)	V
8	Negative Supply Voltage (Pin D/F 7) (Pin C 10)	V <sub>SS</sub>	0	V

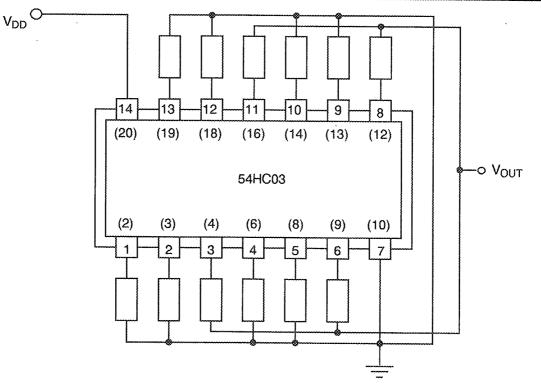
#### <u>NOTES</u>

1. Input Protection Resistor =  $680\Omega$  min. to  $47k\Omega$  max.

2. Output Load =  $1k\Omega$  min. to  $10k\Omega$  max.

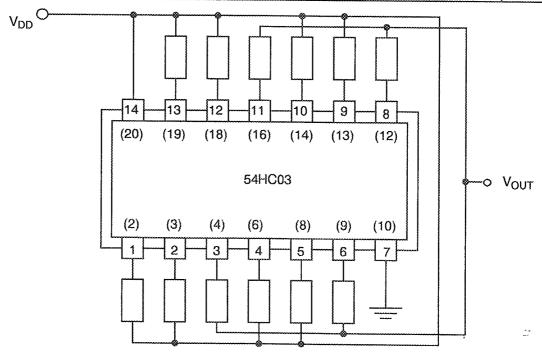


# FIGURE 5(a) - ELECTRICAL CIRCUIT FOR BURN-IN HIGH TEMPERATURE REVERSE BIAS, N-CHANNELS



NOTES 1. Pin numbers in parenthesis are for the chip carrier package.

# FIGURE 5(b) - ELECTRICAL CIRCUIT FOR BURN-IN HIGH TEMPERATURE REVERSE BIAS, P-CHANNELS



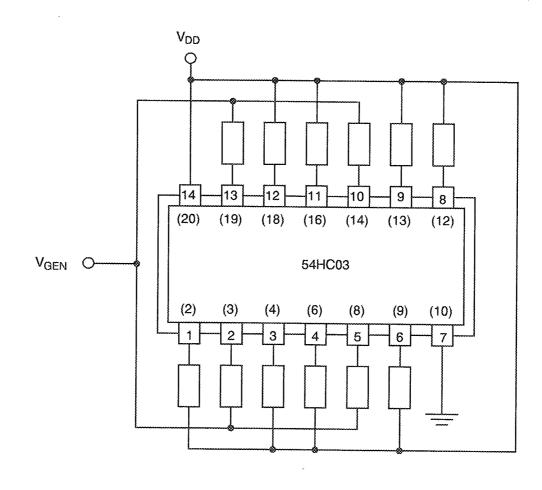
NOTES 1. Pin numbers in parenthesis are for the chip carrier package.



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# FIGURE 5(c) - ELECTRICAL CIRCUIT FOR POWER BURN-IN AND OPERATING LIFE TEST



**NOTES** 1. Pin numbers in parenthesis are for the chip carrier package.



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#### 4.8 <u>ENVIRONMENTAL AND ENDURANCE TESTS (CHARTS IV AND V OF ESA/SCC GENERIC</u> SPECIFICATION NO. 9000)

#### 4.8.1 <u>Electrical Measurements on Completion of Environmental Tests</u>

The parameters to be measured on completion of environmental tests are scheduled in Table 6. Unless otherwise stated, the measurements shall be performed at  $T_{amb} = +22 \pm 3$  °C.

#### 4.8.2 <u>Electrical Measurements at Intermediate Points during Endurance Tests</u>

The parameters to be measured at intermediate points during endurance tests are as scheduled in Table 6 of this specification. Unless otherwise stated, the measurements shall be performed at  $T_{amb} = +22 \pm 3$  °C.

#### 4.8.3 <u>Electrical Measurements on Completion of Endurance Tests</u>

The parameters to be measured on completion of endurance testing are as scheduled in Table 6 of this specification. Unless otherwise stated, the measurements shall be performed at  $T_{amb} = +22 \pm 3$  °C.

#### 4.8.4 Conditions for Operating Life Tests

The requirements for operating life testing are specified in Section 9 of ESA/SCC Generic Specification No. 9000. The conditions for operating life testing shall be as specified in Table 5(c) of this specification.

#### 4.8.5 <u>Electrical Circuits for Operating Life Tests</u>

Circuits for use in performing the operating life tests are shown in Figure 5(c) of this specification.

#### 4.8.6 Conditions for High Temperature Storage Test

The requirements for the high temperature storage test are specified in ESA/SCC Generic Specification No. 9000. The temperature to be applied shall be the maximum storage temperature specified in Table 1(b) of this specification.

#### 4.9 TOTAL DOSE IRRADIATION TESTING

#### 4.9.1 Application

If specified in Para. 4.2.1 of this specification, total dose irradiation testing shall be performed in accordance with the requirements of ESA/SCC Basic Specification No. 22900.

#### 4.9.2 Bias Conditions

Continuous bias shall be applied during irradiation testing as shown in Figure 6 of this specification.

#### 4.9.3 Electrical Measurements

The parameters to be measured prior to irradiation exposure are scheduled in Table 2 of this specification. Only devices which meet the requirements of Table 2 shall be included in the test sample.

The parameters to be measured during and on completion of irradiation testing are scheduled in Table 7 of this specification.



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### TABLE 6 - ELECTRICAL MEASUREMENTS ON COMPLETION OF ENVIRONMENTAL TESTS AND AT INTERMEDIATE POINTS AND ON COMPLETION OF ENDURANCE TESTING

	-				CHANGE	ABSOLUTE		
NO.	CHARACTERISTICS	SYMBOL	SPEC. AND/OR TEST METHOD	TEST CONDITIONS	LIMITS		1	
				CONDITIONS	(Δ) (NOTE 1)	MIN	MAX	
1	Functional Test 1	59	As per Table 2	As per Table 2	-	=	-	-
2	Functional Test 2	-	As per Table 2	As per Table 2	~	~	-	-
3	Functional Test 3	-	As per Table 2	As per Table 2	~	-	-	~
4 to 5	Quiescent Current	ddl	As per Table 2	As per Table 2	±0.03	-	0.1	μΑ
6 to 13	Input Current Low Level	l <u>şı</u>	As per Table 2	As per Table 2	±20	-	-50	nA
14 to 21	Input Current High Level	ĮΗ	As per Table 2	As per Table 2	±20	-	50	nA
34 to 37	Output Voltage Low Level 4	V <sub>OL4</sub>	As per Table 2	As per Table 2	± 0.026	u	0.26	V
38 to 41	Output Voltage Low Level 5	V <sub>OL5</sub>	As per Table 2	As per Table 2	± 0.026	~	0.26	V
42 to 45	Output Current High Level	Юн	As per Table 2	As per Table 2	±0.2	-	0.5	μA
46	Threshold Voltage N-Channel	V <sub>THN</sub>	As per Table 2	As per Table 2	± 0.3	-0.45	-1.45	V
47	Threshold Voltage P-Channel	V <sub>THP</sub>	As per Table 2	As per Table 2	±0.3	0.45	1.35	V

#### **NOTES**

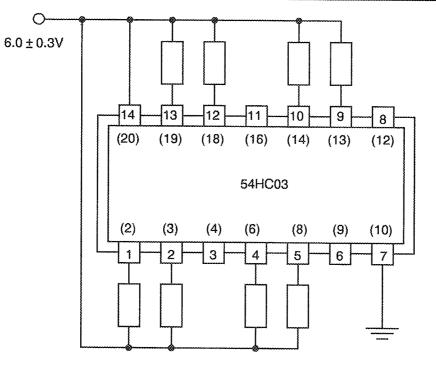
1. The change limits ( $\Delta$ ) are applicable to the Operating Life test only. The change in parameters between initial and end point measurements shall not exceed the limits given. In addition, the absolute limits shall not be exceeded.



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# FIGURE 6 - BIAS CONDITIONS FOR IRRADIATION TESTING



### <u>NOTES</u>

- 1. Pin numbers in parenthesis are for the chip carrier package.
- 2. Input Protection Resistor =  $680\Omega$  min. to  $47k\Omega$  max.



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# TABLE 7 - ELECTRICAL MEASUREMENT DURING AND ON COMPLETION OF IRRADIATION TESTING

NO.	CHARACTERISTICS	SYMBOL	SPEC. AND/OR	TEST	CHANGE	ABSOLUTE		UNIT
			TEST METHOD	CONDITIONS	(Δ)	MIN	MAX	
4 to 5	Quiescent Current	I <sub>DD</sub>	As per Table 2	As per Table 2	-	~	10	μΑ
46	Threshold Voltage N-Channel	V <sub>THN</sub>	As per Table 2	As per Table 2	± 0.6	-0.4	- 1.5	ν
47	Threshold Voltage P-Channel	V <sub>THP</sub>	As per Table 2	As per Table 2	±0.6	0.4	1.4	V



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### APPENDIX 'A'

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# AGREED DEVIATIONS FOR TEXAS INSTRUMENTS (F)

ITEMS AFFECTED	DESCRIPTION OF DEVIATIONS
	Para. 9.9.2, "Electrical Measurements at High and Low Temperatures": Only a test result summary, based on go-no-go- tests and presented in histogram form is required.



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### APPENDIX 'B'

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# AGREED DEVIATIONS FOR STMICROELECTRONICS (F)

ITEMS AFFECTED	DESCRIPTION OF DEVIATIONS
Para. 4.2.3	Para. 7.1.1(b): Power Burn-in test is performed using STMicroelectronics Specification Ref.: 0019255.
Para. 4.2.3	Para. 9.23, High Temperature Reverse Bias Burn-in: The temperature limits of MIL- STD-883, Para. 4.5.8(c) may be used. Para. 9.24, Power Burn-in: The temperature limits of MIL-STD-883, Para. 4.5.8(c) may be used.
Para. 4.2.4	Para. 9.21.1, Operating Life During Qualification Testing: The temperature limits of MIL-STD-883, Para. 4.5.8(c) may be used.
Para. 4.2.5	Para. 9.21.2, Operating Life Test During Lot Acceptance Testing: The temperature limits of MIL-STD-883, Para. 4.5.8(c) may be used.